



QUICKSWITCH® PRODUCTS
HIGH-SPEED CMOS
QUICKSWITCH
DOUBLE-WIDTH BUS SWITCH

IDTQS32X2245

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- Dual '245 function
- 25Ω resistor for low noise
- Low propagation delay, zero ground bounce
- Undershoot clamp diodes on all switch and control inputs
- TTL-compatible control inputs
- Available in 40-pin QVSOP package

APPLICATIONS:

- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Bus switching and isolation
- Power conservation
- Clock gating
- Logic replacement

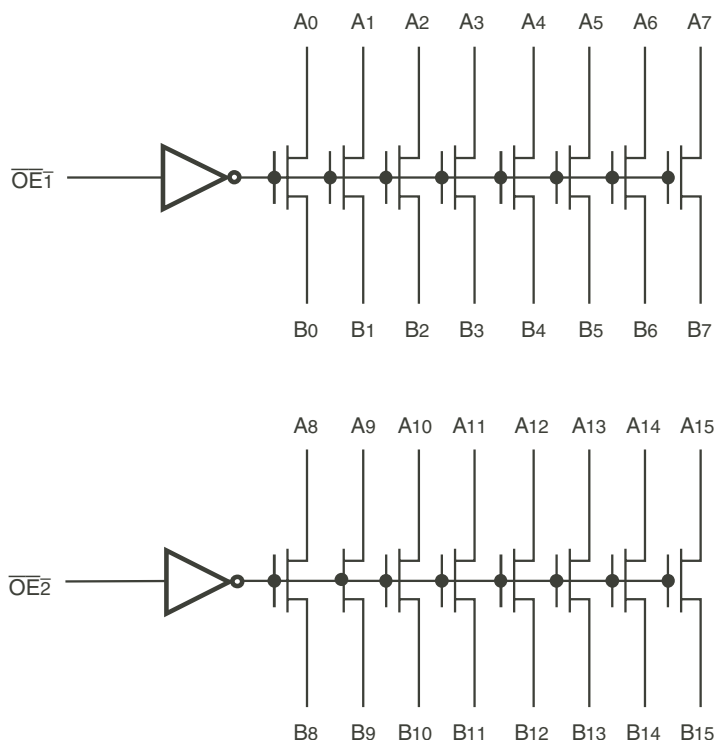
DESCRIPTION:

The QS32X2245 provides a set of 16 high-speed CMOS TTL-compatible bus switches in a flow-through pinout. The QS32X2245 includes internal 25Ω resistors to reduce reflection noise in high speed applications. The Output Enable ($\overline{OE}$) signals turn the switches on similar to the $\overline{OE}$ signal of the 74'245.

QuickSwitch devices provide an order of magnitude faster speed than conventional logic devices.

The QS32X2245 is characterized for operation at -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM

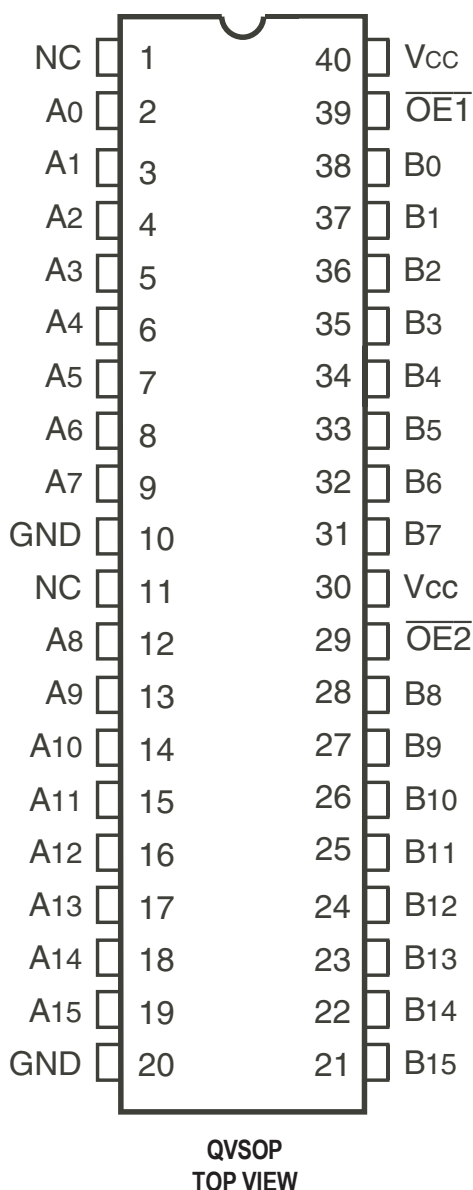


The IDT logo is a registered trademark of Integrated Device Technology, Inc.

INDUSTRIAL TEMPERATURE RANGE

FEBRUARY 2011

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
V _{TERM} ⁽²⁾	Supply Voltage to Ground	-0.5 to +7	V
V _{TERM} ⁽³⁾	DC Switch Voltage V _s	-0.5 to +7	V
V _{TERM} ⁽³⁾	DC Input Voltage V _{IN}	-0.5 to +7	V
V _{AC}	AC Input Voltage (pulse width ≤ 20ns)	-3	V
I _{OUT}	DC Output Current	120	mA
P _{MAX}	Maximum Power Dissipation (T _A = 85°C)	0.92	W
T _{STG}	Storage Temperature	-65 to +150	°C

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{cc} terminals.
- All terminals except V_{cc}.

CAPACITANCE

(T_A = +25°C, f = 1.0MHz, V_{IN} = 0V, V_{OUT} = 0V)

Pins	Typ.	Max. ⁽¹⁾	Unit
Control Pins	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

- This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	I/O	Description
$\overline{OE1}$, $\overline{OE2}$	I	Bus Enable
A _n	I/O	Bus A
B _n	I/O	Bus B

FUNCTION TABLE⁽¹⁾

$\overline{OE1}$	$\overline{OE2}$	A ₀ - A ₇	A ₈ - A ₁₅	Function
H	H	Z	Z	Disconnect
L	H	B ₀ - B ₇	Z	Connect
H	L	Z	B ₈ - B ₁₅	Connect
L	L	B ₀ - B ₇	B ₈ - B ₁₅	Connect

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH for Control Pins	2	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
I_{IN}	Input Leakage Current (Control Inputs) ⁽²⁾	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	± 0.01	± 1	μA
I_{OZ}	Off-State Output Current (Hi-Z)	$0\text{V} \leq V_{OUT} \leq V_{CC}$, Switches OFF	—	± 0.01	± 1	μA
$R_{ON}^{(3)}$	Switch ON Resistance	$V_{CC} = \text{Min.}$, $V_{IN} = 0\text{V}$, $I_{ON} = 30\text{mA}$	18	23	35	Ω
		$V_{CC} = \text{Min.}$, $V_{IN} = 2.4\text{V}$, $I_{ON} = 15\text{mA}$	18	25	40	
V_P	Pass Voltage ⁽²⁾	$V_{IN} = V_{CC} = 5\text{V}$, $I_{OUT} = -5\mu\text{A}$	3.7	4	4.2	V

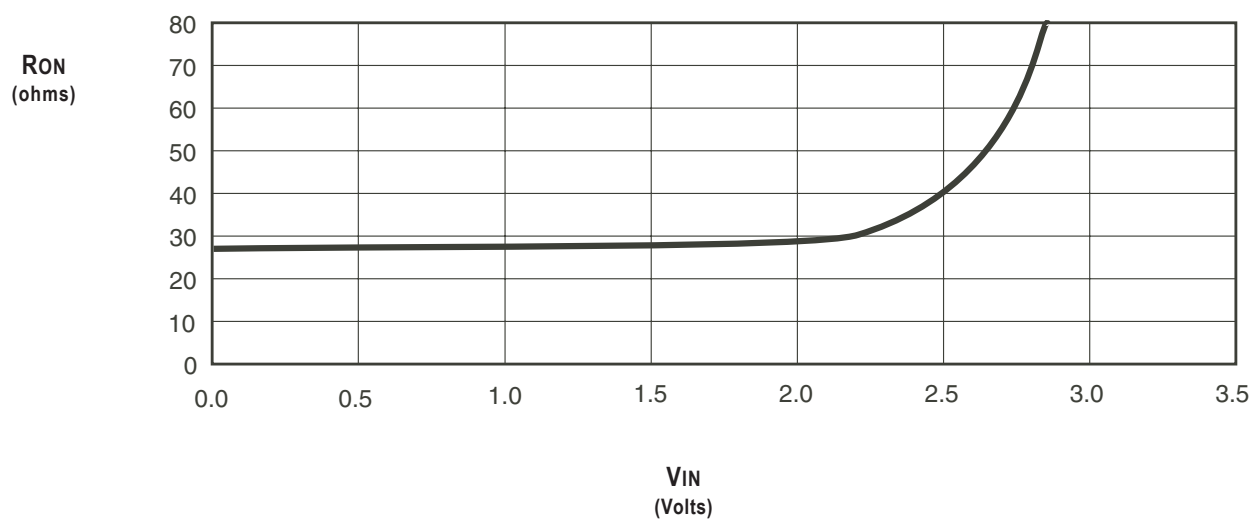
NOTES:

1. Typical values are at $V_{CC} = 5.0\text{V}$, $T_A = 25^{\circ}\text{C}$.

2. Pass Voltage is guaranteed but not production tested.

3. R_{OUT} changed on March 8, 2002. See rear page for more information.

TYPICAL ON RESISTANCE vs V_{IN} AT $V_{CC} = 5\text{V}$



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
I _{CCQ}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC} , f = 0	6	μA
ΔI _{CC}	Power Supply Current per Control Input HIGH ⁽²⁾	V _{CC} = Max., V _{IN} = 3.4V, f = 0	1.5	mA
I _{CCD}	Dynamic Power Supply Current per MHz ⁽³⁾	V _{CC} = Max., A and B pins open Control Inputs Toggling at 50% Duty Cycle	0.25	mA/MHz

NOTES:

- For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- Per TLL driven input (V_{IN} = 3.4V, control inputs only). A and B pins do not contribute to ΔI_{CC}.
- This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C, V_{CC} = 5.0V ± 5%;

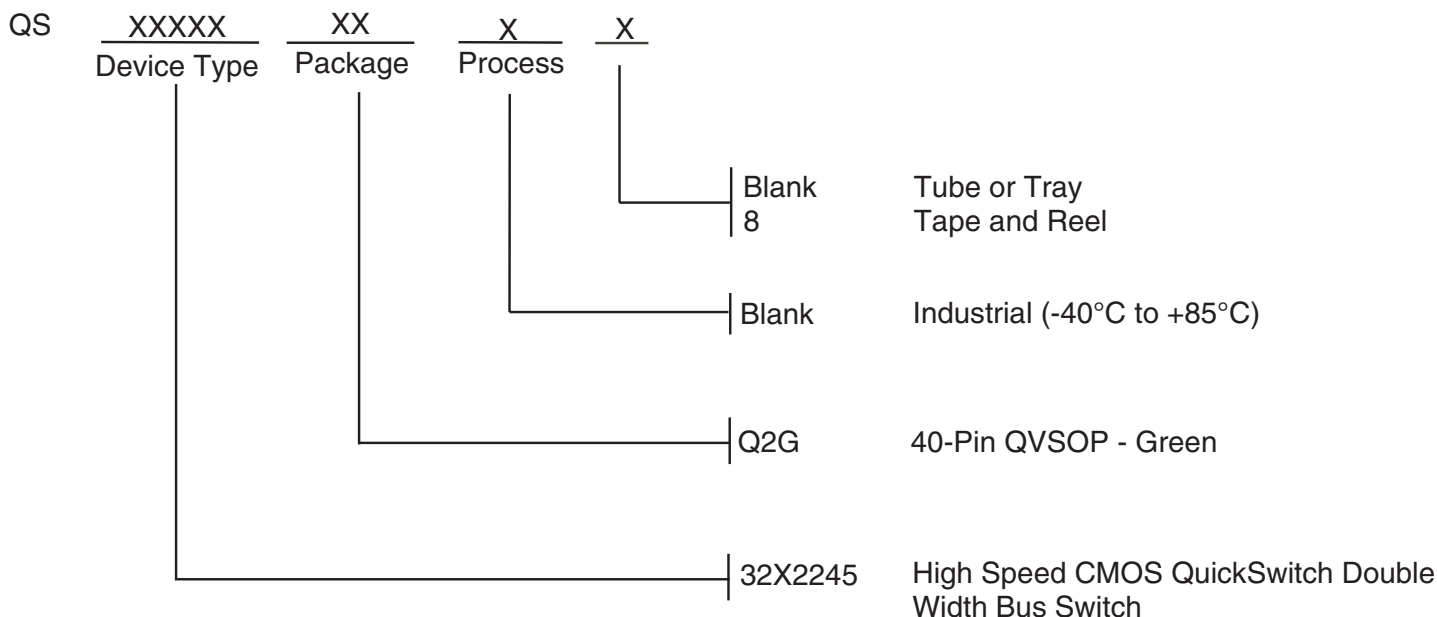
C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Typ.	Max.	Unit
t _{PLH}	Data Propagation Delay ^(2,3)	—	—	1.25	ns
t _{PHL}	An to/from Bn	—	—	—	—
t _{PZL}	Switch Turn-on Delay	0.5	—	6.6	ns
t _{PZH}	$\overline{OE}$ to An/Bn	—	—	—	—
t _{PLZ}	Switch Turn-off Delay ⁽²⁾	0.5	—	4.5	ns
t _{PHZ}	$\overline{OE}$ to An/Bn	—	—	—	—

NOTES:

- Minimums are guaranteed but not production tested.
- This parameter is guaranteed but not production tested.
- The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 1.25ns for C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION



As per PCN L0201-02, the Output Resistance (RON) specifications have changed as of March 8, 2002. The original specifications were:

Parameter	Description	Min.	Typ.	Max.	Unit
RON	Vcc = Min, VIN = 0V, ION = 30mA	20	28	40	Ω
	Vcc = Min, VIN = 2.4V, ION = 15mA	20	35	48	

Datasheet Document History

02/16/2011 Pg. 5 Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information.



CORPORATE HEADQUARTERS
 6024 Silver Creek Valley Road
 San Jose, CA 95138

for SALES:
 800-345-7015 or 408-284-8200
 fax: 408-284-2775
 www.idt.com

for Tech Support:
 logichelp@idt.com

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9